Conserved Spin Quantity in Strained Hole Systems with Rashba and Dresselhaus Spin-Orbit Coupling SFB 689

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Motivation

Poster 2 31

The critical challenge for spintronic devices: control of the carrier spin lifetime, which is limited by the *spin relaxation* and dephasing processes in semiconductors, here of *Dyakonov-Perel type*.

Goal: Following the idea of a non-ballistic spin-field-effect transistor in 2D electron gases [1], find the spinpreserving symmetries to extend the application of spintronic devices to the *non-ballistic/diffusive* regime (with spin-independent scattering) in 2D hole gases (2DHG) in a zincblende type semiconductor heterostructure, including both Rashba (SIA) and Dresselhaus (BIA) spin-orbit coupling (SOC). What are the optimal material parameters? Is it sufficient to tune Rashba/Dresselhaus SOC? What are the persistent spin states (PSS)?

System

Starting point is an effective 4x4 Hamiltonain

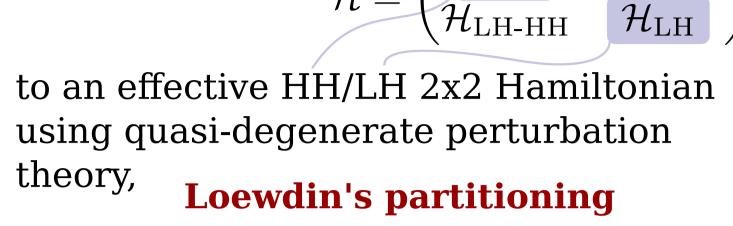
 $\mathcal{H} = \mathcal{H}_{\rm L} + \mathcal{H}_{\rm BIA} + \mathcal{H}_{\rm S} + V,$

with the *Luttinger Hamiltonian* for III-V semiconductors in three dimensions (total angular momentum j=3/2)

$$\mathcal{H}_{\rm L} = -\frac{\hbar^2}{2m_0} \left(\gamma_1 \mathbf{k}^2 - 2\gamma_2 \left[\left(J_x^2 - \frac{1}{3} \mathbf{J}^2 \right) k_x^2 + \text{c.p.} \right] \right]$$

Model The confinement in [001]-direction allows

for a simplification of $\mathcal{H}_{
m HH-LH}$ ' $\mathcal{H}_{\mathrm{HH}}$



 $\mathcal{H} =$

Problems: • Reducing the Rashba contribution [2] in a hole system $\mathcal{H}_{8v8v}^r = \frac{r_{41}^{8v8v}}{r_{41}^{8v8v}} ((k_y \mathcal{E}_z - k_z \mathcal{E}_y) J_x + \text{c.p.})$ to a 2D system: r_{41}^{8v8v} is due to the band-gap splitting, has to be re-calculated including the effect of \implies subband splitting! In general, we have $\gamma_3 > \gamma_2$, however, for PSS in 2DHG with BIA+SIA [2] — Conductance correction 0.10 $\gamma_3 \doteq 0$ In 2DHG with SIA+strain [3]: One finds a PSS only for 0.07 🔨 0.06 ــز 0.05 $\gamma_2 = -\gamma_3$ 0.03 **合** • A correct application of 0.02 5 Loewdin perturbation is non-0.01 trivial. -0.01 suppression 0.02 of spin relaxation -1.5 -0.5 Λ_R/Λ_D

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$$4\gamma_3 [\{J_x, J_y\}\{k_x, k_{,y}\} + \text{c.p.}]],$$

due to bulk inversion asymmetry (BIA)

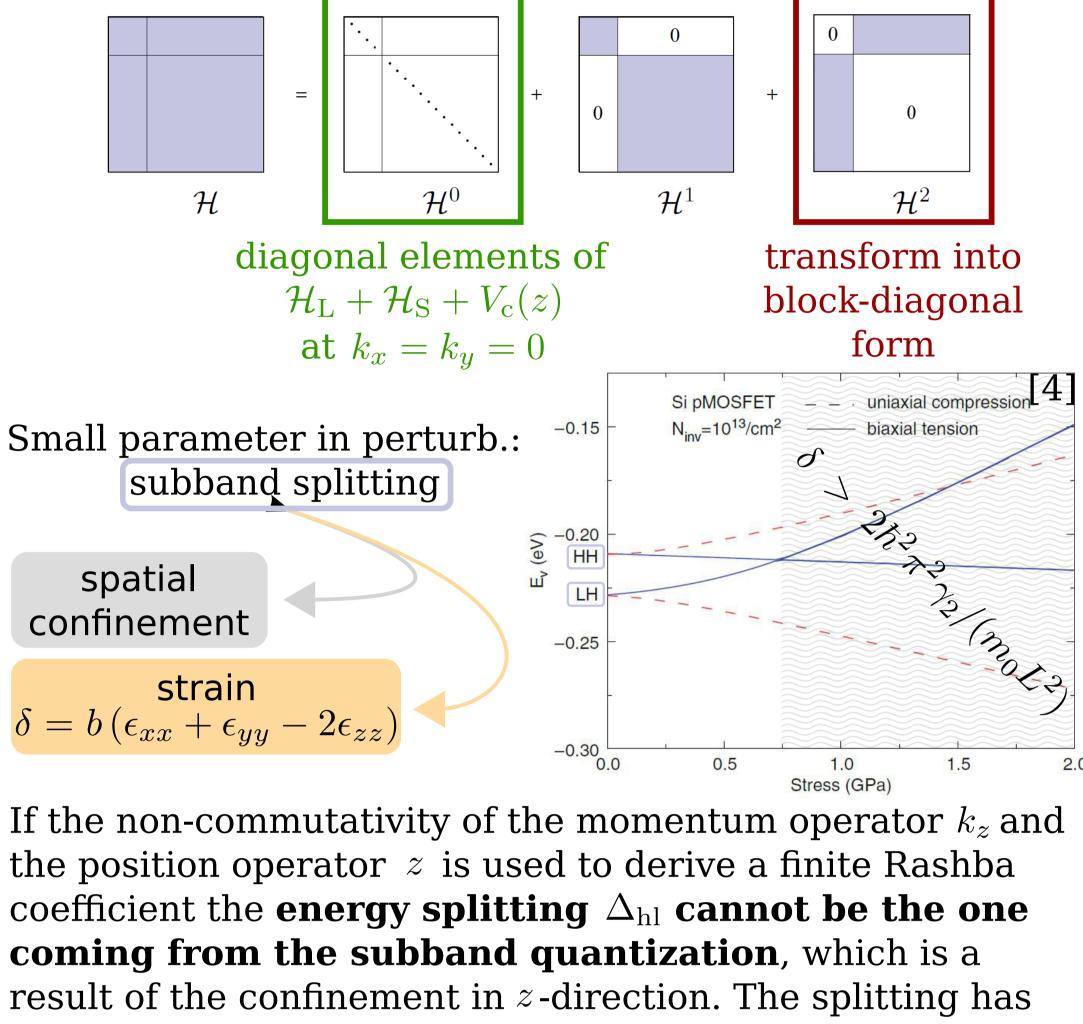
 $\mathcal{H}_{\text{BIA}} = \frac{2}{\sqrt{3}} C_k \left(k_x \{ J_x, J_y^2 - J_z^2 \} + \text{c.p.} \right) + \left(\begin{array}{c} \text{other relativistic terms} \\ \sim b_{42}^{8v8v}, b_{51}^{8v8v}, b_{52}^{8v8v} \end{array} \right)$ $+ b_{41}^{8v8v} \left(\{k_x, k_y^2 - k_z^2\} J_x + \text{c.p.} \right)$

and the *Bir-Pikus Hamiltonian* to include strain

$$\mathcal{H}_{S} = \sum_{i} \left(a \epsilon_{ii} + b \epsilon_{ii} J_{i}^{2} + d \sum_{j, j \neq i} \epsilon_{ij} \{J_{i}, J_{j}\} \right)$$
$$\beta^{2} e^{2i\theta} := \frac{m_{0}}{\hbar^{2} \gamma_{3}} (b (\epsilon_{xx} - \epsilon_{yy}) + 2id\epsilon_{xy})$$

The structure IA (SIA)
contribution is calculated
explicitly by including
$$V_{\rm E}(z) = 1_{4 \times 4} \cdot e \mathcal{E}_z z$$

The lateral confinement,
 $V_{\rm c}(z) =$
 $1_{4 \times 4} \cdot \begin{cases} 0 & \text{for } z \in [0, L] \\ \infty & \text{otherwise.} \end{cases}$



bands

to have another source, e.g., **strain**.

Given a HH(LH) like ground state it is necessary to include, in addition to the the first LH(HH) like subband, also the **second HH(LH) like subband**.

Effective SO Field

Assuming the ground state being HH/LH like and applying third order Loewdin perturbation theory,

$$\mathcal{H}^{\text{eff}} \approx \sum_{i=0}^{3} \left(E_{\text{kin}}^{(i)} + V_{\text{eff}}^{(i)} \right) \cdot \mathbb{1}_{2 \times 2} + \mathbf{\Omega}^{(i)} \cdot \boldsymbol{\sigma}$$

we get for the SO field

$$\begin{split} \Omega_{\rm HH} &= \Omega_{+} \\ \Omega_{\rm LH} &= \Omega_{-} + \Omega_{b} \\ \Omega_{b} &= b_{41}^{8v8v} \left\{ k_{x}k_{y}^{2}, -k_{x}^{2}k_{y}, 0 \right\}^{\top} \\ \Omega_{x,\pm} &= \lambda_{\rm D,\pm} \left\{ k_{x}k_{y}^{2} \left(\gamma_{2} \mp 2\gamma_{3}\right) - k_{x}^{3}\gamma_{2} + \eta_{\pm}k_{x} \\ &+ \beta^{2}\gamma_{3} \left[\pm k_{y} \left(\frac{k_{x}^{2}}{\langle k_{z}^{2} \rangle} - 1 \right) \sin(2\theta) \\ &+ k_{x} \left(\frac{k_{y}^{2}}{\langle k_{z}^{2} \rangle} - 1 \right) \cos(2\theta) \right] \right\} \\ &+ \lambda_{\rm R,\pm} \left[\pm (\gamma_{2} \pm 2\gamma_{3}) k_{x}^{2}k_{y} \mp \gamma_{2}k_{y}^{3} \\ &+ \beta^{2}\gamma_{3} \left(\pm k_{y} \cos(2\theta) + k_{x} \sin(2\theta) \right) \right], \end{split}$$
dependence on shear strain ϵ_{xy} and deformation potential d

Conditions for a Conserved Spin in a 2DHG

[3]

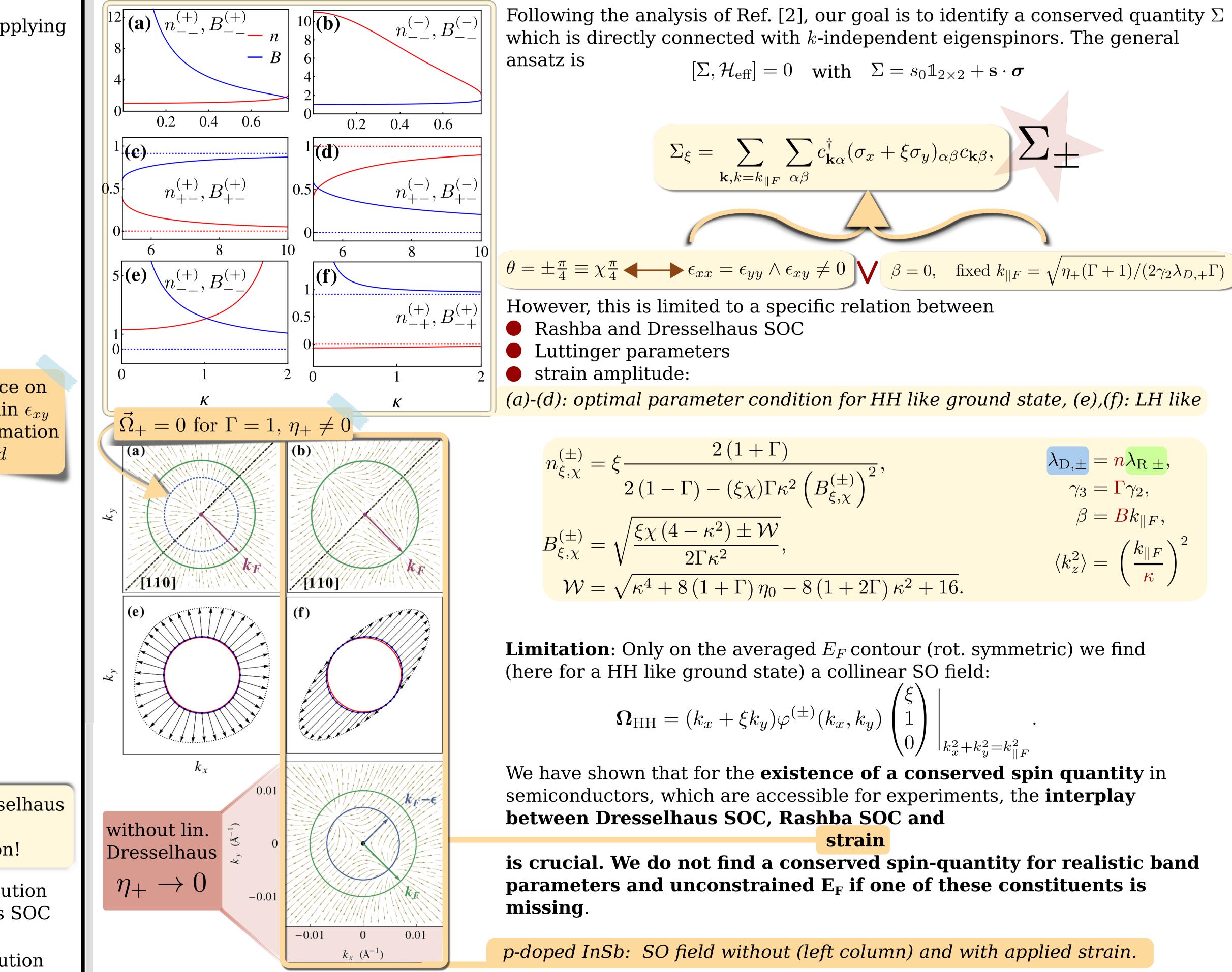
СВ

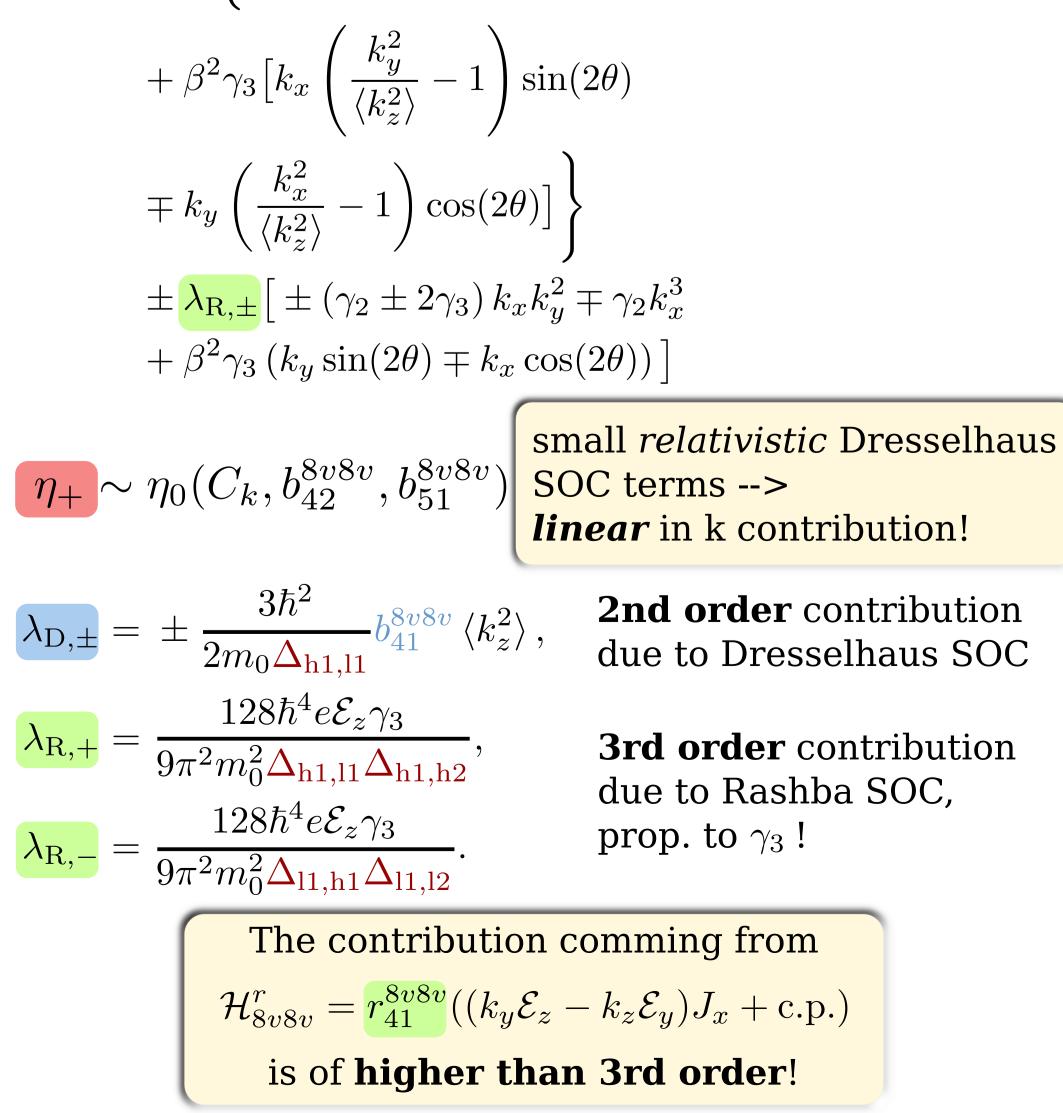
NH 1

HH 2

LH₂

SO





Outlook

- Analysis of long lived spin states in 2DHGs with other growth directions.
- Calculation of weak (anti)localization.
- Dependence of Rashba SOC coefficient on the filling.

Limitation: Only on the averaged E_F contour (rot. symmetric) we find

$$\Omega_{\rm HH} = (k_x + \xi k_y) \varphi^{(\pm)}(k_x, k_y) \begin{pmatrix} \xi \\ 1 \\ 0 \end{pmatrix} \Big|_{k_x^2 + k_y^2}$$

We have shown that for the **existence of a conserved spin quantity** in

is crucial. We do not find a conserved spin-quantity for realistic band

References

[1] Schliemann *et al.*, PRL **90**, 146801 (2003) [2] Dollinger *et al.*, PRB **90**, 115306 (2014) [3] Sacksteder *et al.*, PRB **89**, 161307 (2014) [4] Sun et al., Strain Effects in Semiconductors: Theory and Device Applications, Springer (2010) Poster results: PRB **93**, **115312** (2016)